DATASHEET

4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER AC INPUT PHOTOCOUPLER EL814 Series



Features

- Compliance Halogens Free
- (Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm)
- AC input response
- Current transfer ratio (CTR: Min. 20% at I_F = ±1mA, V_{CE} = 5V)
- High isolation voltage between input and output (Viso = 5000 V rms)
- Wide Operating temperature range -55~110°C
- High collector-emitter voltage V_{CEO} = 80V
- Compact dual-in-line package
- The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

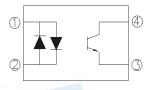
Description

The EL814 series of devices each consist of two infrared emitting diodes, connected in inverse parallel, optically coupled to a phototransistor detector. They are packaged in a 4-pin DIP package and available in side-lead spacing and SMD option.

Applications

- AC line monitor
- Programmable controllers
- Telephone line interface
- Unknown polarity DC sensor

Schematic



- Pin Configuration
- 1. Anode / Cathode
- 2. Cathode / Anode
- Emitter
 Collector

Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	IF	±60	mA
lasut	Peak forward current (t = 10µs)	I _{FM}	1	А
Input	Power dissipation	D	100	mW
	Derating factor (above 100 °C)	P _D —	2.9	mW/ºC
	Power dissipation Derating factor (above 100 ºC)	P _C	150	mW
			5.8	mW/ºC
Output	Collector-Emitter voltage	V _{CEO}	80	V
	Emitter-Collector voltage	V _{ECO}	6	V
Total Powe	er Dissipation	P _{TOT}	200	mW
Isolation V	'oltage*1	V _{ISO}	5000	V rms
Operating Temperature		T _{OPR}	-55 to 110	°C
Storage Te	emperature	T _{STG}	-55 to 125	°C
Soldering	Temperature* ²	T _{SOL}	260	°C

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	VF	-	1.2	1.4	V	$I_F = \pm 20 \text{mA}$
Input capacitance	Cin	-	50	250	pF	V = 0, f = 1KHz
Dutput						
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter dark current	ICEO	-	-	100	nA	$V_{CE} = 20V$, $I_F = 0mA$
Collector-Emitter breakdown voltage	BV _{CEO}	80	-	-	V	$I_C = 0.1 \text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	6	-	-	V	$I_E = 0.1 \text{mA}$
ransfer Characterist	tics					
ransfer Characterist Parameter	t ics Symbol	Min	Тур.	Max.	Unit	Condition
Parameter Current EL814	Symbol	Min 20	Typ. -	Max. 300	5	
Parameter					Unit %	Condition $I_F = \pm 1 \text{mA}$, $V_{CE} = 5V$
Parameter Current EL814 Transfer	Symbol	20		300	5	
Parameter Current Transfer ratio	Symbol	20 50		300 150	5	$I_F = \pm 1 \text{mA}$, $V_{CE} = 5 \text{V}$
Parameter Current Transfer ratio CTR Symmetry Collector-emitter	Symbol	20 50		300 150 2.0	%	$I_F = \pm 1 \text{mA}$, $V_{CE} = 5V$ $I_F = \pm 1 \text{mA}$, $V_{CE} = 5V$
Parameter Current EL814 Transfer atio CTR Symmetry Collector-emitter saturation voltage	Symbol - CTR V _{CE(sat)}	20 50 0.5 -	0.05	300 150 2.0 0.2	% V	$I_F = \pm 1 mA$, $V_{CE} = 5V$ $I_F = \pm 1 mA$, $V_{CE} = 5V$ $I_F = \pm 20 mA$, $I_c = 1 mA$ $V_{IO} = 500Vdc$, 40~60%R.H
Parameter Current Transfer ratio EL814 EL814 EL814A CTR Symmetry Collector-emitter saturation voltage Isolation resistance	Symbol - CTR V _{CE(sat)} R _{IO}	20 50 0.5 - 5×10 ¹⁰	0.05 10 ¹¹	300 150 2.0 0.2	% V Ω	$I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 20 \text{mA}, I_{C} = 1 \text{mA}$ $V_{IO} = 500 \text{Vdc}, 40 \sim 60\% \text{R.H}$ $V_{CE} = 5V, I_{C} = 2 \text{ mA}, R_{L} = 100\Omega$
Parameter Current Transfer ratio EL814 EL814A CTR Symmetry Collector-emitter saturation voltage Isolation resistance Cut-off frequency	Symbol CTR V _{CE(sat)} R _{IO} f _c	20 50 0.5 - 5×10 ¹⁰	0.05 10 ¹¹ 80	300 150 2.0 0.2 - -	% V Ω kHz	$I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 1 \text{mA}, V_{CE} = 5V$ $I_{F} = \pm 20 \text{mA}, I_{C} = 1 \text{mA}$ $V_{IO} = 500 \text{Vdc}, 40 \sim 60\% \text{R.H}$ $V_{CE} = 5V, I_{C} = 2 \text{ mA}, R_{L} = 100\Omega$ $-3dB$

* Typical values at $T_a = 25^{\circ}C$

Figure 2. Normalized Current Transfer Ratio vs Figure 1. Forward Current vs Forward Voltage Forward Current 100 5 Normalized Current Transfer Ratio, CTR T_=25°C Normalized to I_F=5mA V_{CE}=5V 25°C Forward Current, I_F(mA) 10 110°C -55°C 0.1 0.1 0.6 0.8 1.0 1.2 1.4 1.6 1.8 0.5 100 1 10 Forward Voltage, V_F (V) Forward Current, IF (mA) Figure 3. Current Transfer Ratio vs Figure 4. Dark Current vs Ambient Temperature Ambient Temperature 10000 1.4 Normalized Current Transfer Ratio, CTR V_{CE}= 10 V IF=20mA IF=10mA 1.2 1000 Collector Dark Current, I_{CEO} (nA) 1.0 IF=5mA 100 0.8 10 IF=2mA 0.6 IF=1mA 0.4 0.1 0.2 0.01 V_{ce}=5V Normalized to I_=5mA .T.=25°C 1E-3 -60 0.0 -60 -40 -20 0 20 40 60 80 100 120 -40 -20 20 40 60 80 100 120 ò Ambient Temperature Ta (°C) Ambient Temperature, Ta (°C) Figure 5. Collector Current vs Figure 6. Collector Current vs Collector Voltage Collector Voltage 3.0 45 T_≜=25°C T_≜=25°C 40 2.5 I_=20mA Collector Current, I_c (mA) 35 Collector Current, I_C (mA) 2.0 30 I_F=2mA 25 1.5 20 I_=10mA 15 1.0 I_=1mA 10 I_F=5mA 0.5 5 I_=0.5mA I_=1mA 0.0 L 0.0 0 0 2 4 6 10 0.4 1.0 0.2 0.6 0.8 Collector Emitter Voltage, $V_{_{CE}}$ (V) Collector Emitter Voltage, V_{CE} (V)

Typical Electro-Optical Characteristics Curves

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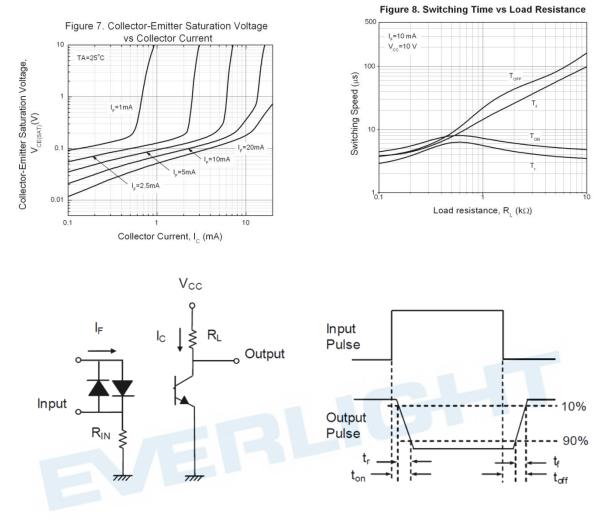


Figure 9. Switching Time Test Circuit & Waveforms

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Lord Series

Order Information

Part Number

EL814X(Y)(Z)-V

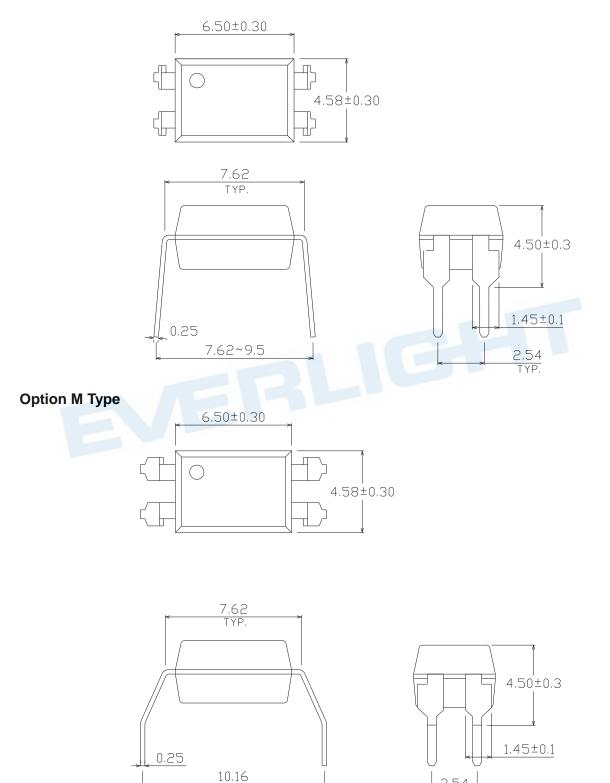
Notes

- X = Lead form option (S, S1, M or none)
- Y = CTR Rank (A or none)
- Z = Tape and reel option (TA, TB, TU, TD or none)
- V = VDE safety (optional)

Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel

Package Dimension (Dimensions in mm)

Standard DIP Type

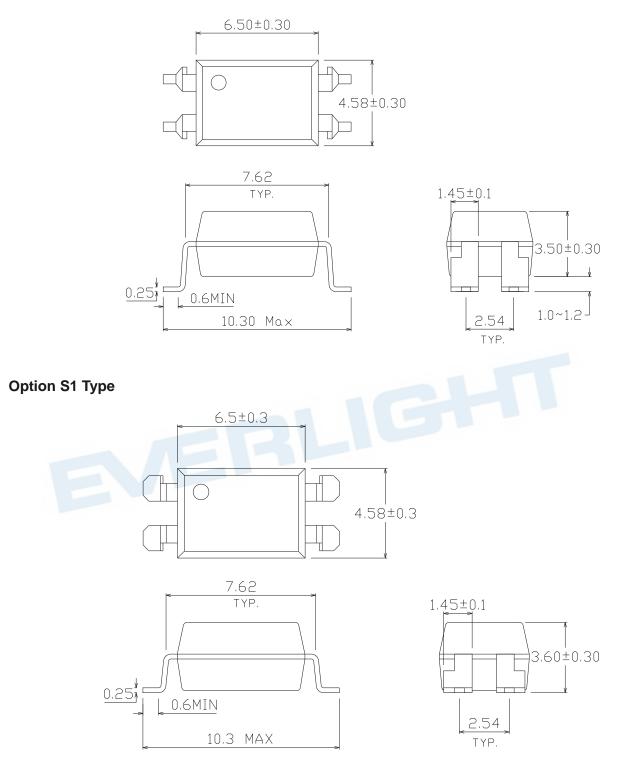


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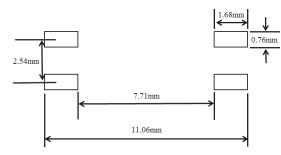
Option S Type

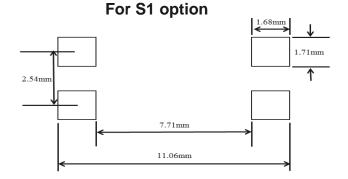


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Recommended pad layout for surface mount leadform

For S option





Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

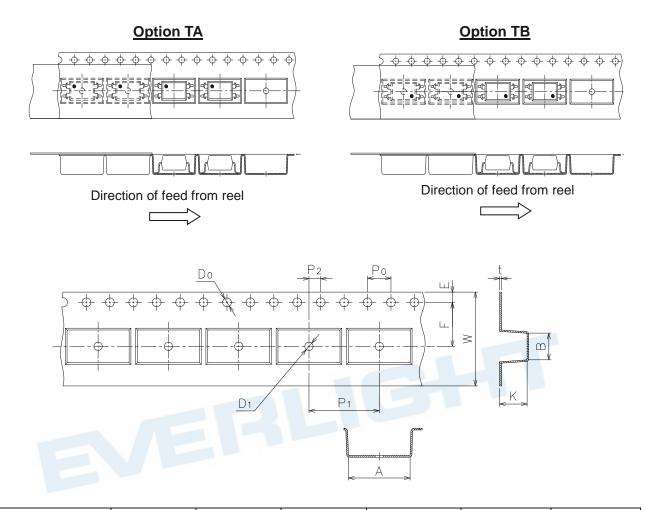
Device Marking



Notes

EL	denotes EVERLIGHT
814	denotes Device Number
R	denotes CTR Rank (A or none)
Υ	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

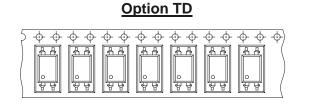
Tape & Reel Packing Specifications



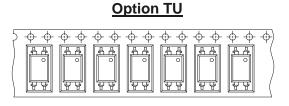
Dimension No.	Α	В	Do	D1	Е	F
Dimension (mm) S	10.7±0.1	4.65±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.5±0.1
Dimension (mm) S1	10.7±0.1	4.65±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	W	к
Dimension No. Dimension (mm) S	Po 4.0±0.1	P1 12.0±0.1	P2 2.0±0.1	t 0.4±0.1	W 16.0±0.3	К 4.75±0.1

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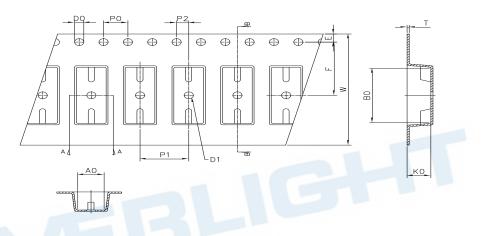
Direction of feed from reel



Direction of feed from reel

 \Rightarrow

Tape dimensions



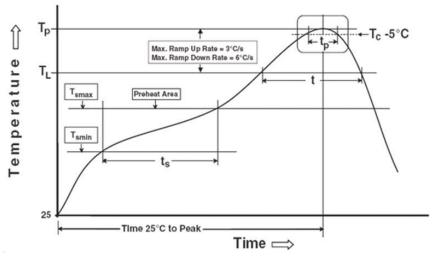
Dimension No.	Ао	Во	Do	D1	Е	F
Dimension (mm) S.S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension No.	Ро	P1	P2	4	W	Ко
	10	E I	ΓZ	Ľ	vv	NU



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Notes

Preheat

Reflow times

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Treneat	
Temperature min (T _{smin})	150 °C
Temperature max (T _{smax})	200°C
Time (T _{smin} to T _{smax}) (t _s)	60-120 seconds
Average ramp-up rate (T _{smax} to T _p)	3 °C/second max
Other	
Liquidus Temperature (T _L)	217 °C
Time above Liquidus Temperature (t ∟)	60-100 sec
Peak Temperature (T _P)	260°C
Time within 5 °C of Actual Peak Temperature: T_P - 5°C	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature	8 minutes max.

Reference: IPC/JEDEC J-STD-020D

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3 times

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